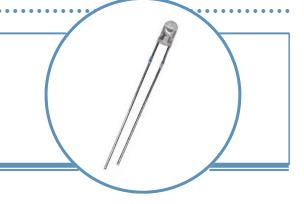
Round Through-Hole LED Lamp (3 mm)



OVLBx4C7 Series

- High brightness with well-defined spatial radiation patterns
- UV-resistant epoxy lens
- Lead-frame material is iron alloy with tin plated leads
- No stand-offs

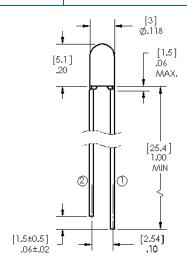


Each **OVLBx4C7** series device is a high-intensity LED mounted in a clear plastic T-1 package. The LED provides a well-defined and even emission pattern. Its UV-resistant epoxy lens makes this device an optimal solution for outdoor applications.

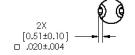
Applications

- Pedestrian signals
- · Signage and architectural lighting
- Backlighting
- Automotive
- Outdoor/indoor displays

Part Number	Material	Emitted Color	Intensity Typ. mcd	Lens Color
OVLBB4C7	InGaN	Blue	1800	Clear
OVLBG4C7	IIIGain	Green	8400	Clear
OVLBR4C7	AllaCaD	Red	3700	Clear
OVLBY4C7	AllnGaP	Yellow	3700	Clear







① ANODE ② CATHODE

General tolerance +/- .25mm unless specified

Dimensions are in Inches [MM]

DO NOT LOOK DIRECTLY AT LED WITH UNSHIELDED EYES OR DAMAGE TO RETINA MAY OCCUR.



Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Storage Temperature Range		-40 ~ +100 ℃
Operating Temperature Range		-40 ~ +100 ℃
Reverse Voltage (Device not designed for reverse voltage applications)		5 V Max
Continuous Famurant Comment (5)	Blue, Green	25 mA
Continuous Forward Current (Design of heat dissipation should be considered)	Red, Yellow	50 mA
Dealt Familiard Comment (1994 D. 1994	Blue, Green	100 mA
Peak Forward Current (10% Duty Cycle, 1 kHz)	Red, Yellow	100 mA
Device Dissinction	Blue, Green	100 mW
Power Dissipation	Red, Yellow	120 mW
Comment Linearity on Ambient Tenanguature	Blue, Green	-0.29 mA/°C
Current Linearity vs Ambient Temperature	Red, Yellow	-0.72 mA/°C
LED Junction Temperature		125°C
Electrostatic Discharge Classification (JEDEC-JESD22-A114F)		Class 1C
Lead Soldering Temperature (4 mm away from the base of the epoxy bulb)		260°C / 3 seconds

Electrical Characteristics (T_A = 25°C unless otherwise noted)

SYMBOL	PARAMETER	COLOR	MIN	TYP	MAX	UNITS	CONDITIONS	
		Blue	1135	1800				
ı	Luminous Intensity	Green	4360	8400		mcd	I _F = 20 mA	
I _V	Luminous intensity	Red	2225	3700		IIICa	I _F = 20 IIIA	
		Yellow	2225	3700				
		Blue	2.6	3.2	4.0			
V _F	Forward Voltage	Green	2.0	3.2	4.0	V	I - 20 m 1	
VF	Forward Voltage	Red	Red 1.8 2.0 2.4	v	I _F = 20 mA			
		Yellow	1.8	2.0	2.4			
		Blue						
	Reverse Current	Green			10		$V_R = 5 V$	
I _R	Reverse Current	Red			10	μA	v _R = 5 v	
		Yellow						
		Blue	460	470	475			
1	Dominant Wayalanath	Green	519	525	531 nm	nm	l – 20 mΛ	
λ_{D}	Dominant Wavelength	Red	620	623		11111	$I_F = 20 \text{ mA}$	
		Yellow	585	589	595			
2Θ1⁄2H-H	50% Power Angle			45		deg	I _F = 20 mA	



Standard Bins

LEDs are sorted to luminous intensity (I_V) , forward voltage (V_F) and dominant wavelength (nm) bins listed below. Each bag consists of a single intensity bin, single voltage bin and a single color bin. Orders are filled using all intensity and color bins listed in the following tables. Optek will not accept orders for single intensity bins, single voltage bins or single color bins.

Luminous Intensity (I_V) @ 20mA

Blue: OVLBB4C7					
IV Code	Min (mcd)	Max (mcd)			
0\$	1,135	1,590			
0T	1,590	2,225			
0U	2,225	3,115			
0V	3,115	4,360			
Gre	Green: OVLBG4C7				
IV Code	Min (mcd)	Max (mcd)			
OW	4,360	6,105			
0X	6,105	8,550			
0Y	8,550	11,970			
0Z	11,970	16,758			

Forward Voltage (V_F)

Blue: OVLBB4C7 & Green: OVLBG4C7				
VF Code	Min	Max		
Α	2.6	2.8		
В	2.8	3.0		
С	3.0	3.2		
D	3.2	3.4		
E	3.4	3.6		
F	3.6	3.8		
G	3.8	4.0		

Dominant Wavelength (nm)

Blue: OVLBB4C7						
nm Code	Min	Max				
ВС	460	465				
BD	465	470				
BE	470	475				
Gre	Green: OVLBG4C7					
nm Code	Min	Max				
FB	519	523				
FC	523	527				
FD	527	531				

Luminous Intensity (I_V) @ 20mA

Red: OVLBR4C7					
IV Code	Min (mcd)	Max (mcd)			
0U	2,225	3,115			
0V	3,115	4,360			
OW	4,360	6,105			
Yel	Yellow: OVLBY4C7				
IV Code	Min (mcd)	Max (mcd)			
0U	2,225	3,115			
0V	3,115	4,360			
OW	4,360	6,105			

Forward Voltage (V_F)

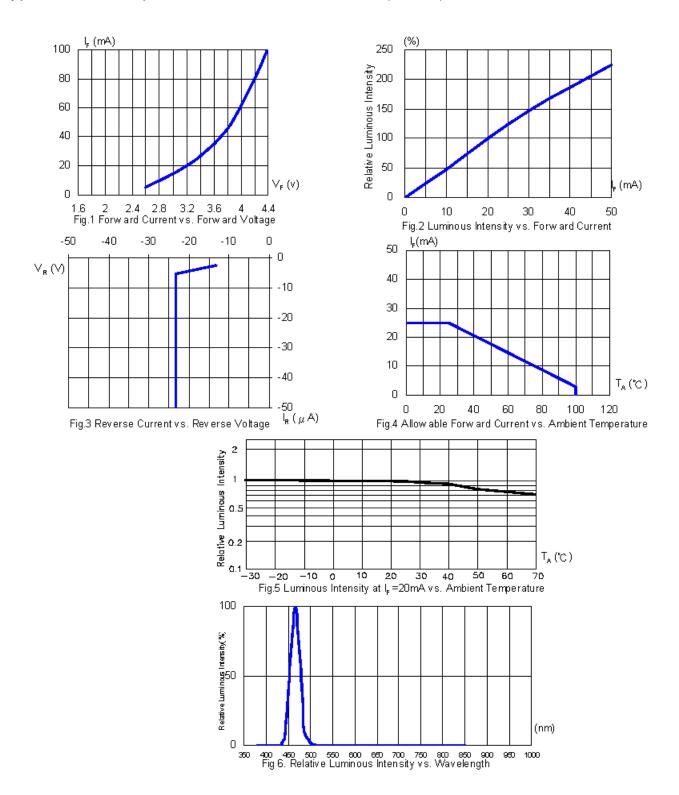
Red: OVLBR4C7 & Yellow: OVLBY4C7				
VF Code	Min Max			
Α	1.8	2.0		
В	2.0	2.2		
С	2.2	2.4		

Dominant Wavelength (nm)

Red: OVLBR4C7					
Min	Max				
620	625				
625	630				
Yellow: OVLBY4C7					
Min	Max				
585	587				
587	589				
589	591				
591	593				
593	595				
	Min 620 625 low: OVLBY4 Min 585 587 589				

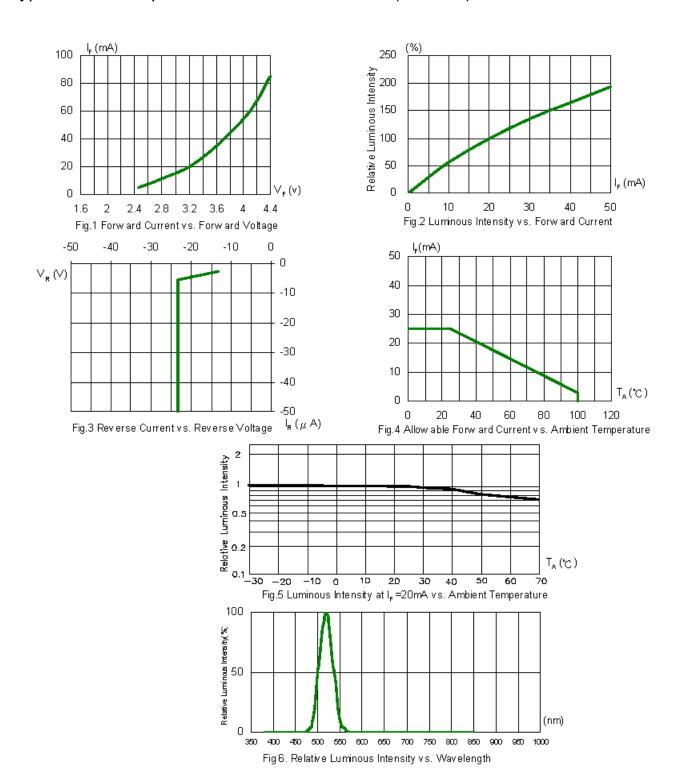


Typical Electro-Optical Characteristics Curves (BLUE)



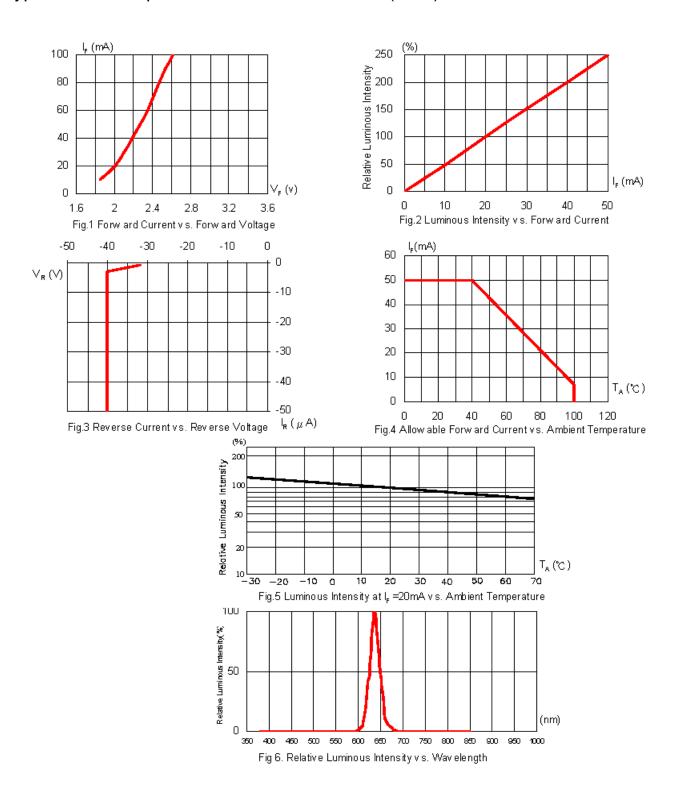


Typical Electro-Optical Characteristics Curves (GREEN)



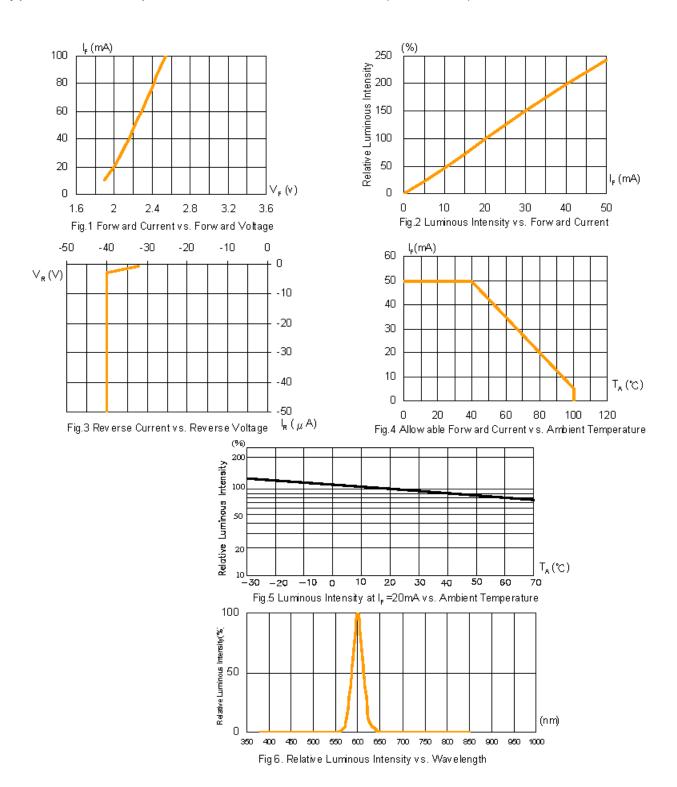


Typical Electro-Optical Characteristics Curves (RED)





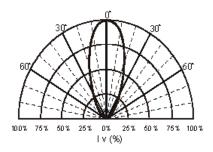
Typical Electro-Optical Characteristics Curves (YELLOW)



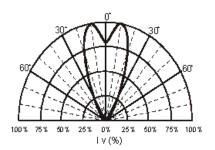


Beam Pattern:

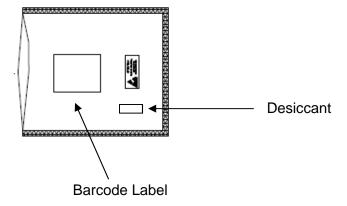
(Blue) and (Green)



(Red) and (Yellow)



Packaging: 500 pcs per bulk bag with desiccant





Reliability Test

LED lamps are checked by reliability tests based on MIL standards.

Classi- fication	Test Item	Standard Test Method	Test Conditions	Duration	Unit	Acc / Rej Criteria	Result
Life Test	Operation Life Test	MIL-STD-750D Method 1026.3	$T_A=25^{\circ}C$, $I_F=30mA$ *	1000 Hrs	100	0 / 1	Pass
Test	(OLT)						
	High Temperature	MIL-STD-750D	T _A =100°C	1000 Hrs	100	0 / 1	Pass
	Storage (HTS)	Method 1032.1	1A-100 C	1000 ms	100	0 / 1	Pass
	Low Temperature	MIL-STD-750D	T ₄ =−40°C	1000 11	100	0/1	ъ
Test	Storage (LTS)	Method 1032.1	1 _A =-40 C	1000 Hrs	100	0 / 1	Pass
lent	Temp. & Humidity	MIL-STD-750D	T -05% - D1-050/ I -20 A **	500 11	100	0.71	,
nuo	with Bias (THB)	Method 103B	$T_A=85^{\circ}C$, Rh=85% $I_F=20mA$ **	500 Hrs	100	0 / 1	Pass
Environment Test	Thermal Shock	MIL-STD-750D	0°C ~ 100°C	100	100	0 / 1	Pass
_	Test (TST)	Method 1056.1	2min 2min	cycles	100	0/1	Pass
	Temperature	MIL-STD-750D	-40°C ~ 25°C~ 100°C ~ 25°C	100	100	0 / 1	Pass
	Cycling Test (TCT)	Method 1051.5	30min 5min 30min 5min	cycles	100	0/1	Pass
	6-11177	MIL-STD-750D	2251590 - 5	1.4	20	0 / 1	D
lest	Solderability	Method 2026.4	235±5°C → 5 sec	1 time	20	0 / 1	Pass
ical	Resistance to	MIL-STD-750D	260±5°C ,10 sec	1 41	20	0 / 1	Dave
Mechanical Test	Soldering Heat	Method 2031.1	200 <u>1</u> 3 (1 time	20	0/1	Pass
Мес	I and Internity	MIL-STD-750D		2 times	2 4	0 / 1	D
	Lead Integrity	Method 2036.3	$0^{\circ} \sim 90^{\circ} \sim 0^{\circ}$, bend	3 times	20	0 / 1	Pass

Remark : (*) $I_F = 30$ mA for AlInGaP chip ; $I_F = 20$ mA for InGaN chip (**) $I_F = 20$ mA for AlInGaP chip ; $I_F = 10$ mA for InGaN chip

2. Failure Criteria ($T_A = 25^{\circ}C$):

Test Item	Symbol	Test Conditions	Criteria for	: Judgment	
rest item	Symbol	Test Conditions	Min.	Max.	
Luminous Intensity	$I_{ m V}$	I _F =20 mA	LSL×0.7 **		
Voltage (Forward)	V_{F}	I _F =20 mA		USL×1.1 *	

(*) USL : Upper Standard Level , (**) LSL : Lower Standard Level